

## SPTECH Silicon NPN Darlington Power Transistor

TIP142P

**DESCRIPTION**

- High DC Current Gain-  
:  $h_{FE} = 1000$ (Min)@  $I_C = 5A$
- Collector-Emitter Sustaining Voltage-  
:  $V_{CEO(SUS)} = 100V$ (Min)
- Complement to Type TIP147

**APPLICATIONS**

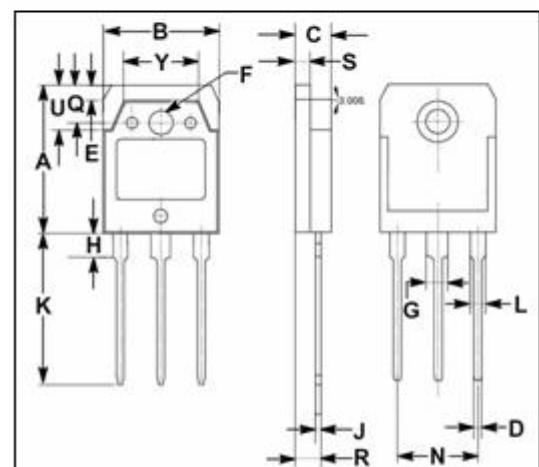
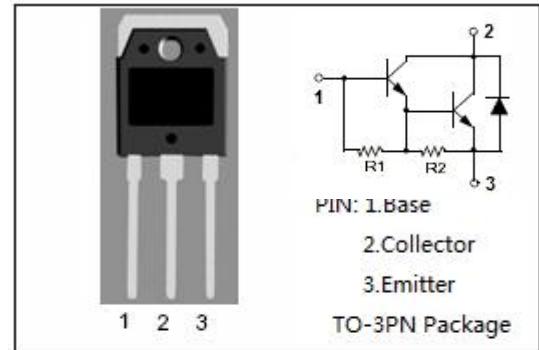
- Designed for general purpose amplifier and low frequency switching applications.

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ C$ )**

| SYMBOL    | PARAMETER                                      | VALUE   | UNIT |
|-----------|--|---------|------|
| $V_{CBO}$ | Collector-Base Voltage                         | 100     | V    |
| $V_{CEO}$ | Collector-Emitter Voltage                      | 100     | V    |
| $V_{EBO}$ | Emitter-Base Voltage                           | 5       | V    |
| $I_C$     | Collector Current-Continuous                   | 10      | A    |
| $I_{CM}$  | Collector Current-Peak                         | 15      | A    |
| $I_B$     | Base Current- Continuous                       | 0.5     | A    |
| $P_c$     | Collector Power Dissipation @ $T_c=25^\circ C$ | 125     | W    |
| $T_j$     | Junction Temperature                           | 150     | °C   |
| $T_{stg}$ | Storage Temperature Range                      | -65~150 | °C   |

**THERMAL CHARACTERISTICS**

| SYMBOL        | PARAMETER                              | MAX  | UNIT |
|---------------|--|------|------|
| $R_{th\ j-c}$ | Thermal Resistance, Junction to Case   | 1.0  | °C/W |
| $R_{th\ j-a}$ | Thermal Resistance,Junction to Ambient | 35.7 | °C/W |



| DIM | mm    |       |
|-----|-------|-------|
|     | MIN   | MAX   |
| A   | 19.60 | 20.30 |
| B   | 15.50 | 15.70 |
| C   | 4.70  | 4.90  |
| D   | 0.90  | 1.10  |
| E   | 1.90  | 2.10  |
| F   | 3.40  | 3.60  |
| G   | 2.90  | 3.20  |
| H   | 3.20  | 3.40  |
| J   | 0.595 | 0.605 |
| K   | 19.80 | 20.70 |
| L   | 1.90  | 2.20  |
| N   | 10.89 | 10.91 |
| Q   | 4.90  | 5.10  |
| R   | 3.35  | 3.45  |
| S   | 1.995 | 2.100 |
| U   | 5.90  | 6.20  |
| Y   | 9.90  | 10.10 |

# SPTECH Product Specification

## SPTECH Silicon NPN Darlington Power Transistor

**TIP142P**

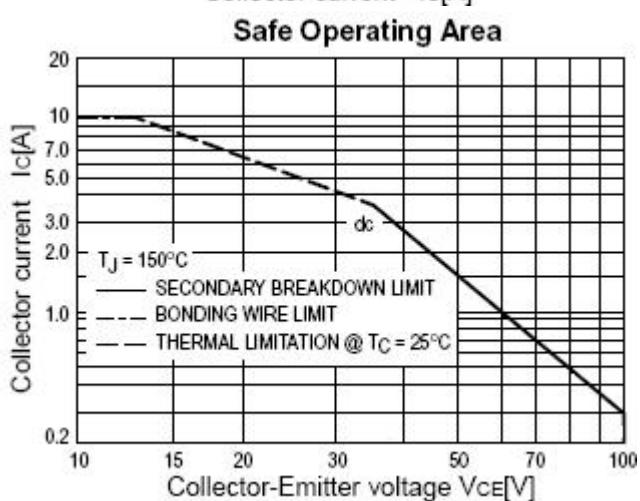
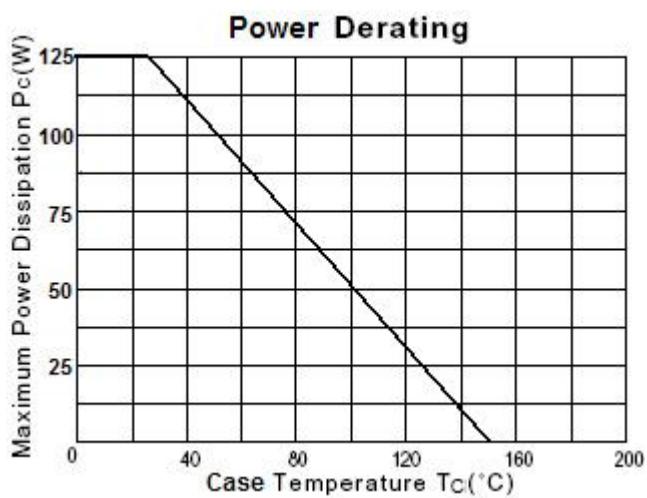
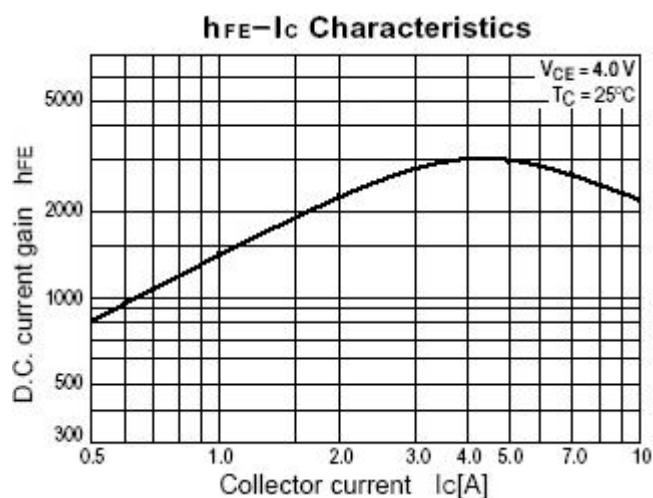
### ELECTRICAL CHARACTERISTICS

$T_c=25^\circ\text{C}$  unless otherwise specified

| SYMBOL                 | PARAMETER                            | CONDITIONS                                | MIN  | TYP. | MAX | UNIT |
|------------------------|--------------------------------------|---|------|------|-----|------|
| $V_{CEO(\text{sus})}$  | Collector-Emitter Sustaining Voltage | $I_C = 30\text{mA}$ , $I_B = 0$           | 100  |      |     | V    |
| $V_{CE(\text{sat})-1}$ | Collector-Emitter Saturation Voltage | $I_C = 5\text{A}$ , $I_B = 10\text{mA}$   |      |      | 2.0 | V    |
| $V_{CE(\text{sat})-2}$ | Collector-Emitter Saturation Voltage | $I_C = 10\text{A}$ , $I_B = 40\text{mA}$  |      |      | 3.0 | V    |
| $V_{BE(\text{sat})}$   | Base-Emitter Saturation Voltage      | $I_C = 10\text{A}$ , $I_B = 40\text{mA}$  |      |      | 3.5 | V    |
| $V_{BE(\text{on})}$    | Base-Emitter On Voltage              | $I_C = 10\text{A}$ ; $V_{CE} = 4\text{V}$ |      |      | 3.0 | V    |
| $I_{CBO}$              | Collector Cutoff current             | $V_{CB} = 100\text{V}$ , $I_E = 0$        |      |      | 1   | mA   |
| $I_{CEO}$              | Collector Cutoff current             | $V_{CE} = 50\text{V}$ , $I_B = 0$         |      |      | 2   | mA   |
| $I_{EBO}$              | Emitter Cutoff Current               | $V_{EB} = 5\text{V}$ ; $I_C = 0$          |      |      | 2   | mA   |
| $h_{FE-1}$             | DC Current Gain                      | $I_C = 5\text{A}$ ; $V_{CE} = 4\text{V}$  | 1000 |      |     |      |
| $h_{FE-2}$             | DC Current Gain                      | $I_C = 10\text{A}$ ; $V_{CE} = 4\text{V}$ | 500  |      |     |      |

### Switching Times

|           |              |   |  |      |  |                |
|-----------|--------------|---|--|------|--|----------------|
| $t_d$     | Delay Time   | $V_{CC} = 30\text{ V}$ , $I_C = 5.0\text{ A}$ ,<br>$I_B = 20\text{ mA}$ ;<br>Duty Cycle $\leq 20\%$<br>$I_{B1} = I_{B2}$ ,<br>$R_C$ & $R_B$ Varied,<br>$T_J = 25^\circ\text{C}$ |  | 0.15 |  | $\mu\text{ s}$ |
| $t_r$     | Rise Time    |   |  | 0.55 |  | $\mu\text{ s}$ |
| $t_{stg}$ | Storage Time |   |  | 2.5  |  | $\mu\text{ s}$ |
| $t_f$     | Fall Time    |   |  | 2.5  |  | $\mu\text{ s}$ |

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